



GADIR
NEXT SOLAR GENERATION

Thin film GADIR a-SiT photovoltaic module

Gadir a-SiT Translucent

The GADIR a-SiT solar module is manufactured with amorphous silicon using state-of-the-art manufacturing techniques, which offer strong competitive advantages over other technologies.

Cost efficient

Thin film Amorphous module's manufacturing process requires significantly less energy input and 99% less silicon compared to crystalline modules. This lower cost per unit produced, combined with a higher energy return on energy invested, translates into a faster payback time.

Higher energy yield

Due to its low temperature coefficient, and a better yield on non tilted installations and in diffuse light conditions, amorphous silicon modules outperform other modules by generating more energy per installed unit power.

This module is therefore especially suitable for all climatic regions especially for warmer even if the orientation is not optimal. Apart from its other strengths, its esthetical design allows it to perfectly adapt as a building integrated photovoltaic solution.

The Gadir a-SiT panel is manufactured under stringent quality controls. Production takes place in a highly modern factory using an integrated automated production line from leading Swiss Oerlikon Solar. The technology is based on the plasmatic deposition of a fine amorphous silicon layer.

The factory

The plant, located in the Bay of Cadiz, Spain, operates with an annual production of more than 40 MW.

Warranties

5 years warranty against materials/manufacturing defects.

Power warranty: 90% of nominal power for the first 10 years and 80% from then on according to warranty terms.



Qualified, IEC 61646
Safety tested, IEC 61730
Periodic inspection



Certification TÜV, IEC 61646, 61730 IEC and security class II.

DE00006.04

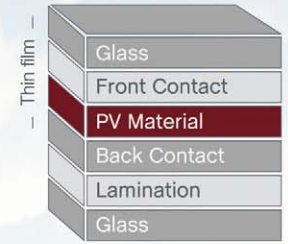


Module structure

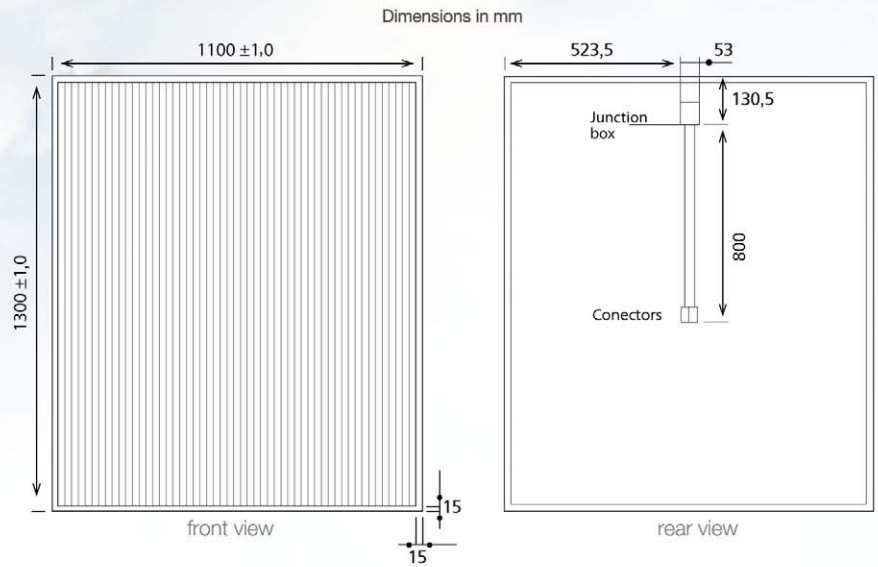
Front Glass	Float Glass 3,2 mm
Cell	Single Junction a- Si PIN
Lamination	Encapsulated Polyvinyl Butyral (PVB)
Rear Glass	Tempered Glass 3,2 mm
Frame	Frameless

Dimensions and Weight

Length	1300 ± 1 mm
Width	1100 ± 1 mm
Thickness	7,2 mm
Weight	25,5 kg



Module characteristics



Stabilized Values⁽¹⁾

	Pmpp ⁽²⁾	Vmpp	Imp	Voc	Isc (w)
GADIR a-Si.T.70	70	96	0,74	137	0,98
GADIR a-Si.T.75	75	101	0,75	137	0,98
GADIR a-Si.T.80*	80	103	0,77	137	0,99
GADIR a-Si.T.85*	85	104	0,81	138	1,02
GADIR a-Si.T.90*	90	104	0,86	138	1,08
GADIR a-Si.T.95	95	105	0,90	138	1,14

Power in Watts

Initial Values

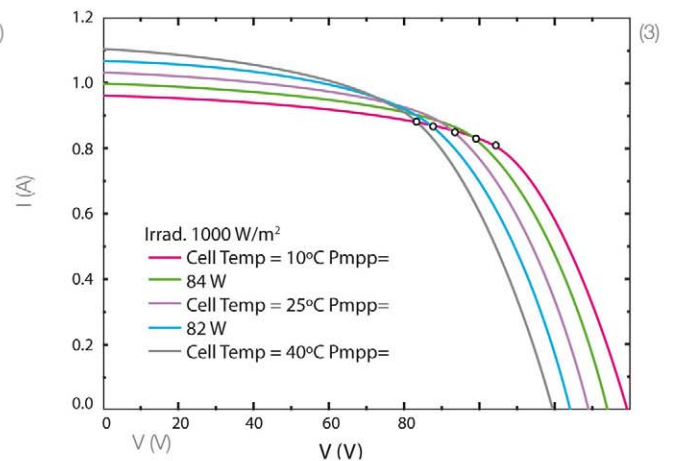
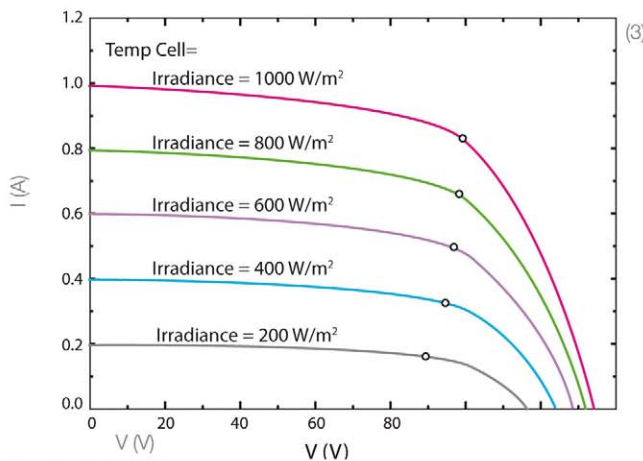
	Pmpp	Vmpp	Imp	Voc	Isc (w)
	91	108	0,84	144	1,01
	97	113	0,86	144	1,01
	104	116	0,89	144	1,02
	110	117	0,93	145	1,05
	117	119	0,98	145	1,11
	123	121	1,03	145	1,17

Power in Watts

Thermal Characteristics

Temperature Range	-40°...85°C
Isc Temperature Coefficient	+0,04 %/K
Voc Temperature Coefficient	-0,28 %/K
Pmpp Temperature Coefficient	-0,21 %/K
Imp Temperature Coefficient	+0,09%/K
Vmpp Temperature Coefficient	-0,29%/K

(1) The parameters represent best current knowledge and are indicative. Garantee is given on STC: 1000 W/m²; AM=1,5; T=25°C. (2) Pmpp Tolerance ±2,5 Wp.
 (*) TÜV Certified.



(3) Curves showing typical values.